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Discrete POWER & Signal **Technologies**

2N5962



MMBT5962



NPN General Purpose Amplifier

This device is designed for use as low noise, high gain, general purpose amplifiers requiring collector currents to 50 mA. Sourced from Process 07. See 2N5088 for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	45	V
V _{CBO}	Collector-Base Voltage	45	V
V _{EBO}	Emitter-Base Voltage	8.0	V
Ic	Collector Current - Continuous	100	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах		Units
		2N5962	*MMBT5962	
P _D	Total Device Dissipation	625	350	mW
	Derate above 25°C	5.0	2.8	mW/°C
$R_{\theta_{JC}}$	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

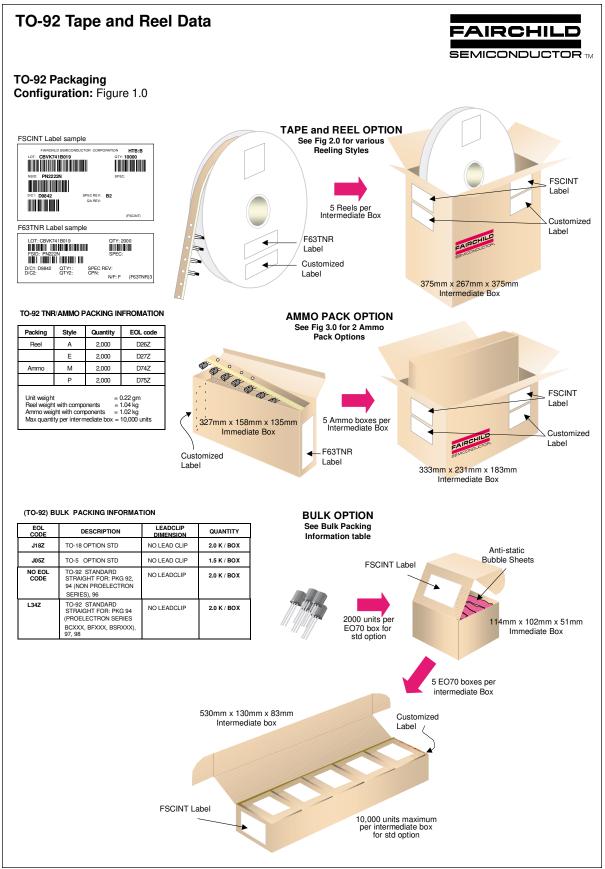
*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

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NPN General Purpose Amplifier (continued)

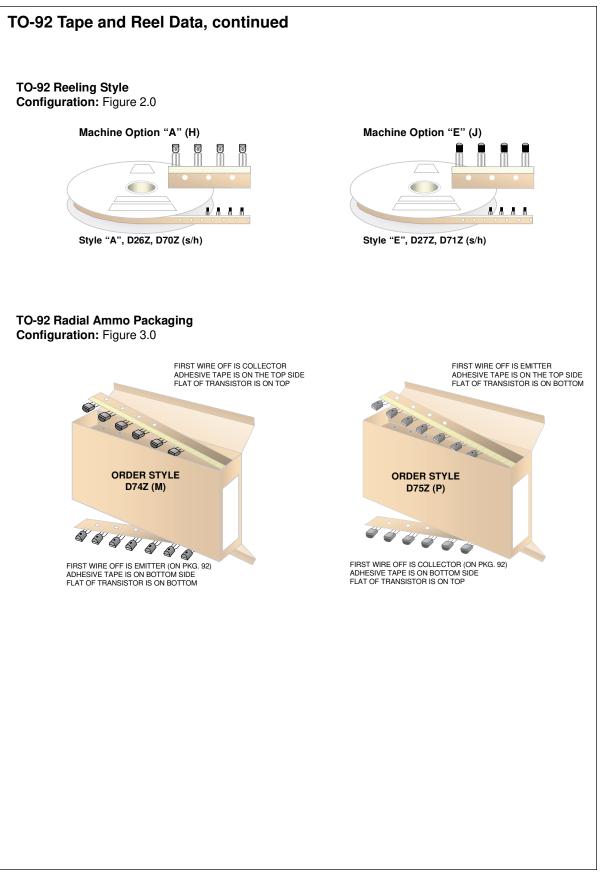
Symbol	Parameter	Test Conditions	Min	Мах	Units
OFF CHA	RACTERISTICS				
(BR)CEO	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 5.0 \text{ mA}, I_{\rm B} = 0$	45		V
(BR)CBO	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu A, \ I_{\rm E} = 0$	45		V
(BR)EBO	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$	8.0		V
BO	Collector Cutoff Current	$V_{CB} = 30 \text{ V}, I_E = 0$ $V_{CB} = 30 \text{ V}, I_E = 0, T_A = 65 \text{ °C}$		2.0 50	nA nA
BO	Emitter Cutoff Current			1.0	nA
ON CHAF	ACTERISTICS*	·		•	•
FE	DC Current Gain	$V_{CE} = 5.0 \text{ V}, I_{C} = 10 \mu\text{A}$	450		
		$V_{CE} = 5.0 \text{ V}, I_C = 100 \ \mu\text{A}$	500		
		$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$	550	1 400	
	Collector-Emitter Saturation Voltage	$V_{CE} = 5.0 \text{ V}, I_C = 10 \text{ mA}$ $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$	600	1400 0.2	V
/ _{CE(sat)} / _{BE(on)}	Base-Emitter On Voltage	$V_{CE} = 5.0 \text{ V}, I_C = 1.0 \text{ mA}$	0.5	0.2	V
SMALL S	IGNAL CHARACTERISTICS Collector-Base Capacitance	V _{CB} = 5.0 V	[4.0	pF
vcb veb				4.0	p p
v oh	Emittor Baco, Capacitanoo	$V_{} = 0.5 V$		60	nE
	Emitter-Base Capacitance	$V_{EB} = 0.5 V$		6.0	pF
	Emitter-Base Capacitance Small-Signal Current Gain	$I_{\rm C} = 10 \text{ mA}, V_{\rm CE} = 5.0 \text{ V},$	600		pF
	•		600	6.0 200	pF
fe	Small-Signal Current Gain	$I_{c} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 1.0 kHz $I_{c} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 100 MHz	600 1.0		pF
fe	•	$\begin{split} & I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, \\ & f = 1.0 \text{ kHz} \\ & I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, \\ & f = 100 \text{ MHz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 10 \mu\text{A}, \end{split}$			pF
fe	Small-Signal Current Gain	$I_{c} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 1.0 kHz $I_{c} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 100 MHz			pF
fe	Small-Signal Current Gain			200	
fe	Small-Signal Current Gain			200	dB
fe	Small-Signal Current Gain	$\begin{split} & I_{C} = 10 \text{ mA}, \text{V}_{CE} = 5.0 \text{ V}, \\ & f = 1.0 \text{kHz} \\ & I_{C} = 10 \text{ mA}, \text{V}_{CE} = 5.0 \text{ V}, \\ & f = 100 \text{MHz} \\ \hline & \text{V}_{CE} = 5.0 \text{ V}, I_{C} = 10 \mu\text{A}, \\ & \text{R}_{s} = 10 \text{k}\Omega, \text{f} = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ \hline & \text{V}_{CE} = 5.0 \text{ V}, \text{I}_{C} = 100 \mu\text{A}, \\ & \text{R}_{s} = 1.0 \text{k}\Omega, \text{f} = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ \end{split}$		200	
fe	Small-Signal Current Gain			200 3.0 6.0	dB
IF	Small-Signal Current Gain	$\begin{split} & I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, \\ & f = 1.0 \text{ kHz} \\ & I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, \\ & f = 100 \text{ MHz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 10 \mu\text{A}, \\ & R_{S} = 10 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz}, \\ & B_{W} = 400 \text{ Hz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}, \\ & R_{S} = 1.0 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz}, \\ & B_{W} = 400 \text{ Hz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}, \\ & R_{S} = 10 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz}, \\ & B_{W} = 400 \text{ Hz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}, \\ & R_{S} = 10 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz}, \\ & B_{W} = 400 \text{ Hz} \end{split}$		200	dB
fe	Small-Signal Current Gain	$\begin{split} & I_{C} = 10 \text{ mA}, \text{V}_{CE} = 5.0 \text{ V}, \\ & f = 1.0 \text{kHz} \\ & I_{C} = 10 \text{ mA}, \text{V}_{CE} = 5.0 \text{ V}, \\ & f = 100 \text{MHz} \\ & \text{V}_{CE} = 5.0 \text{ V}, I_{C} = 10 \mu\text{A}, \\ & \text{R}_{S} = 10 \text{k}\Omega, \text{f} = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, I_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 1.0 \text{k}\Omega, \text{f} = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, I_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 10 \text{k}\Omega, \text{f} = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, I_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 10 \text{k}\Omega, \text{f} = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, I_{C} = 100 \mu\text{A}, \\ \end{array}$		200 3.0 6.0	dB
fe	Small-Signal Current Gain	$\begin{split} & I_{C} = 10 \text{ mA}, \text{ V}_{CE} = 5.0 \text{ V}, \\ & f = 1.0 \text{ kHz} \\ & I_{C} = 10 \text{ mA}, \text{ V}_{CE} = 5.0 \text{ V}, \\ & f = 100 \text{ MHz} \\ & \text{V}_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 10 \mu\text{A}, \\ & \text{R}_{S} = 10 \text{k}\Omega, f = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, \text{ I}_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 1.0 \text{k}\Omega, f = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, \text{ I}_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 10 \text{k}\Omega, f = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, \text{ I}_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 100 \text{k}\Omega, f = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, \text{ I}_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 100 \text{k}\Omega, f = 1.0 \text{kHz}, \end{split}$		200 3.0 6.0	dB
fe	Small-Signal Current Gain	$\begin{split} & I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, \\ & f = 1.0 \text{ kHz} \\ & I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, \\ & f = 100 \text{ MHz} \\ \hline & V_{CE} = 5.0 \text{ V}, I_{C} = 10 \mu\text{A}, \\ & R_{S} = 10 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz}, \\ & B_{W} = 400 \text{ Hz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}, \\ & R_{S} = 1.0 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz}, \\ & B_{W} = 400 \text{ Hz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}, \\ & R_{S} = 10 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz}, \\ & B_{W} = 400 \text{ Hz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}, \\ & R_{S} = 100 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz}, \\ & B_{W} = 400 \text{ Hz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}, \\ & R_{S} = 100 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz}, \\ & B_{W} = 400 \text{ Hz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}, \\ & R_{S} = 100 \text{ k}\Omega, \text{ f} = 1.0 \text{ kHz}, \\ & B_{W} = 400 \text{ Hz} \\ & V_{CE} = 5.0 \text{ V}, I_{C} = 10 \mu\text{A}, \\ & H_{C} = 5.0 \text{ V},$		200 3.0 6.0 4.0	dB dB dB
fe	Small-Signal Current Gain	$\begin{split} & I_{C} = 10 \text{ mA}, \text{ V}_{CE} = 5.0 \text{ V}, \\ & f = 1.0 \text{ kHz} \\ & I_{C} = 10 \text{ mA}, \text{ V}_{CE} = 5.0 \text{ V}, \\ & f = 100 \text{ MHz} \\ & \text{V}_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 10 \mu\text{A}, \\ & \text{R}_{S} = 10 \text{k}\Omega, f = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, \text{ I}_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 1.0 \text{k}\Omega, f = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, \text{ I}_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 10 \text{k}\Omega, f = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, \text{ I}_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 100 \text{k}\Omega, f = 1.0 \text{kHz}, \\ & \text{B}_{W} = 400 \text{Hz} \\ & \text{V}_{CE} = 5.0 \text{V}, \text{ I}_{C} = 100 \mu\text{A}, \\ & \text{R}_{S} = 100 \text{k}\Omega, f = 1.0 \text{kHz}, \end{split}$		200 3.0 6.0 4.0	dB dB dB

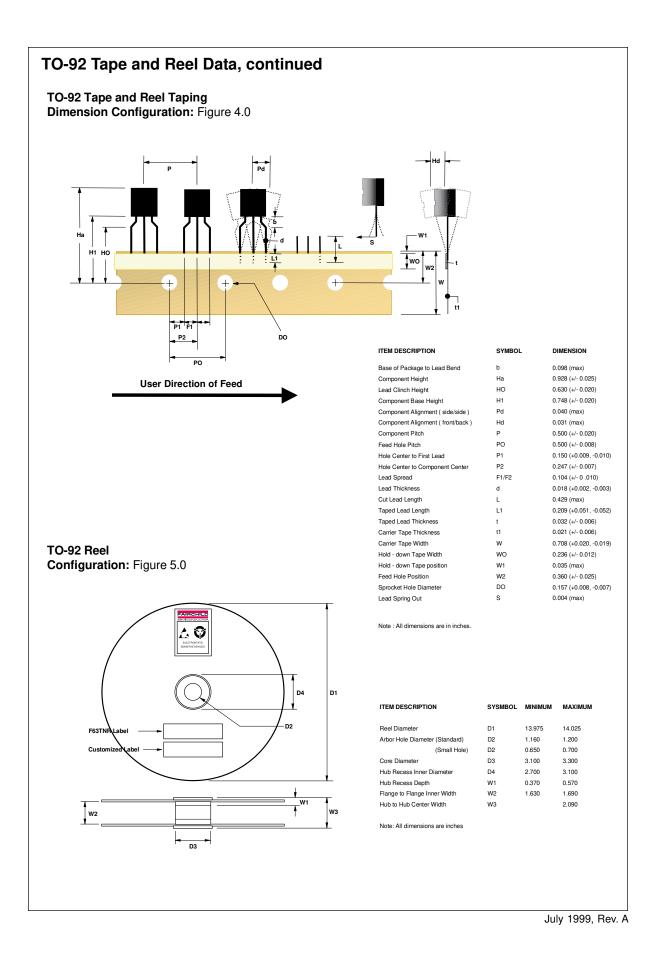
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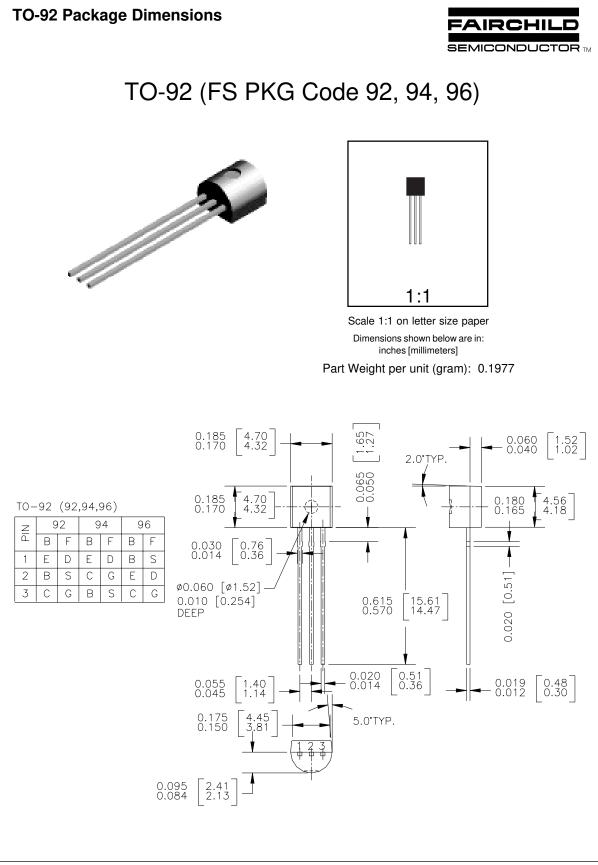


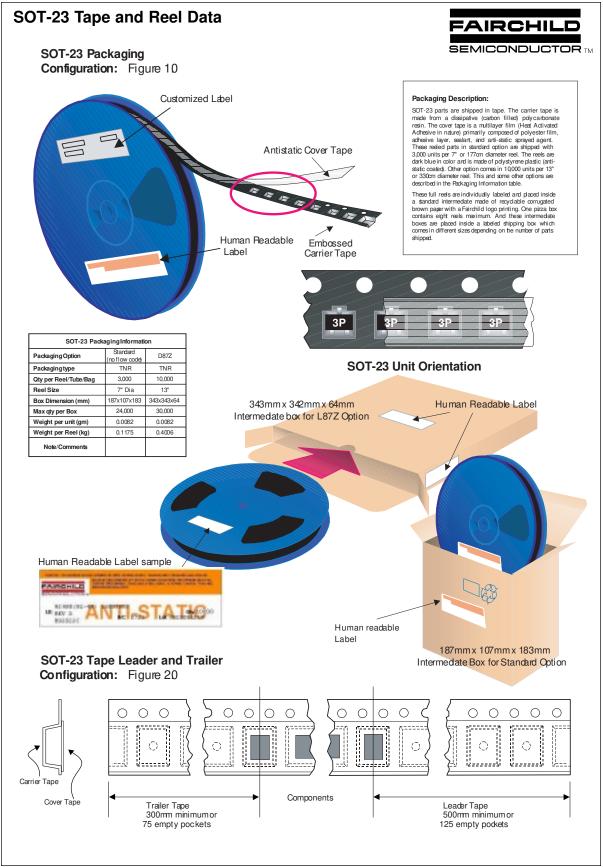
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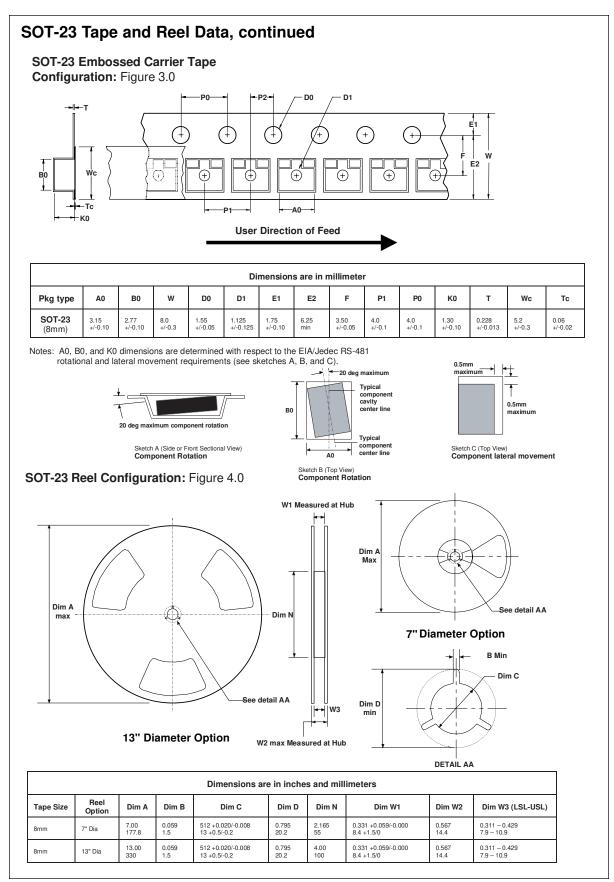




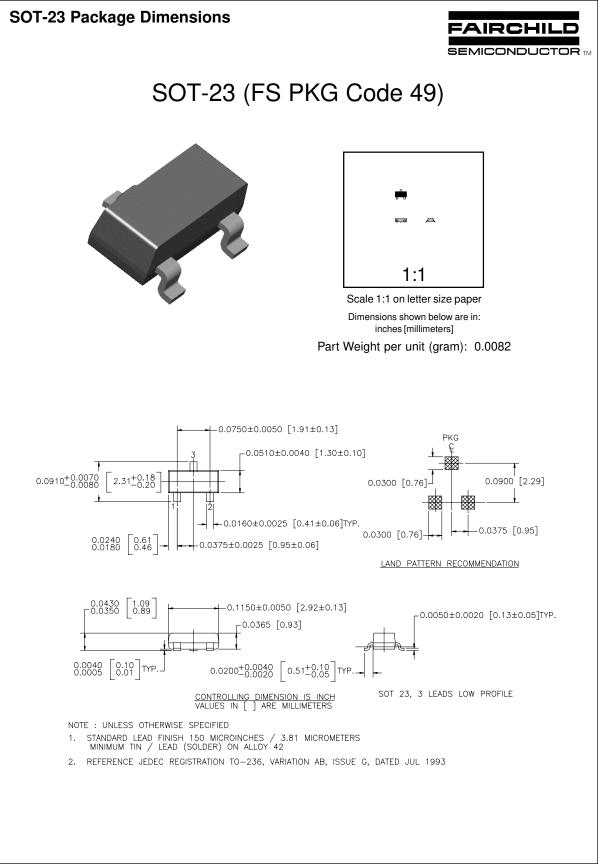


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